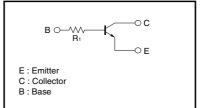
# Digital transistors (built-in resistor) DTC343TK / DTC343TS

#### Features

In addition to the features of regular digital transistors,

- 1) Low V<sub>CE(sat)</sub> makes these transistors ideal for muting circuits. (Typ. 0.04V at I<sub>C</sub>/I<sub>B</sub>=50/2.5mA)
- 2) They can be used at high current. (I<sub>CMax</sub>. =600mA)

#### •Circuit schematic



#### ●Absolute maximum ratings (Ta=25°C)

| Parameter                   |                       | Symbol | Limits      | Unit |
|-----------------------------|-----------------------|--------|-------------|------|
| Collector-base voltag       | ollector-base voltage |        | 30          | V    |
| Collector-emitter voltage   |                       | VCEO   | 15          | V    |
| Emitter-base voltage        |                       | Vebo   | 5           | V    |
| Collector current           |                       | lc     | 600         | mA   |
| Collector power dissipation | DTC343TK              | De     | 200         | mW   |
|                             | DTC343TS              | - Pc   | 300         |      |
| unction temperature         |                       | Tj     | 150         | °C   |
| Storage temperature         |                       | Tstg   | -55 to +150 | °C   |

#### •Package, marking, and packaging specifications

| Part No.                     | DTC343TK | DTC343TS |  |
|------------------------------|----------|----------|--|
| Package                      | SMT3     | SPT      |  |
| Marking                      | H03      | -        |  |
| Packaging code               | T146     | TP       |  |
| Basic ordering unit (pieces) | 3000     | 5000     |  |

#### •External characteristics (Ta=25°C)

| Parameter                            | Symbol   | Min. | Тур. | Max. | Unit | Conditions                       |
|--------------------------------------|----------|------|------|------|------|----------------------------------|
| Collector-base breakdown voltage     | ВУсво    | 30   | _    | -    | V    | Ic=50μA                          |
| Collector-emitter breakdown voltage  | BVCEO    | 15   | _    | -    | V    | Ic=1mA                           |
| Emitter-base breakdown voltage       | BVEBO    | 5    | _    | -    | V    | Ιε=50μΑ                          |
| Collector cutoff current             | Ісво     | _    | _    | 0.5  | μA   | V <sub>CB</sub> =20V             |
| Emitter cutoff current               | Іево     | -    | _    | 0.5  | μA   | VEB=4V                           |
| Collector-emitter saturation voltage | VCE(sat) | _    | 40   | 80   | mV   | Ic=50mA , Iв=2.5mA               |
| DC current transfer ratio            | hfe      | 100  | 250  | 600  | -    | Ic=50mA , Vce=5V                 |
| Input resistance                     | R1       | 3.29 | 4.7  | 6.11 | kΩ   | _                                |
| Transition frequency                 | f⊤       | -    | 200  | -    | MHz  | Vce=10V , Ie= -50mA , f=100MHz * |
| Output on resistance                 | Ron      | -    | 0.95 | -    | Ω    | VI=7V , R=1kΩ , f=1kHz           |

 $\ast Transition$  frequency of the device.



## Transistors

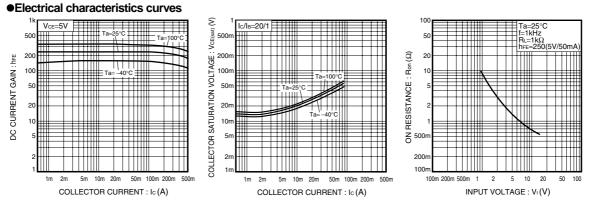


Fig.1 DC current gain vs. Collector current Fig.2 Collector-emitter saturation voltage vs. Collector current

Fig.3 ON resistance vs. Input voltage

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